

Large-Area Fast Micro-channel Plate Photo-detectors

Yi Qiang

SoLID Meeting

Jan 15, 2013

Large-Area Pico-second Photo Detector (LAPPD)

- Newly funded by DOE and NSF (fall '09)
 - 4 National Labs
 - 5 Divisions at Argonne
 - 3 US small companies;
 - Electronics expertise at UofC and Hawaii
 - Photocathode expertise at Washington University, St. Louis and UIC
- Premise:
 - Apply advances in material science and nanotechnology to develop new, batch methods for producing cheap, large area photo-detectors
 - Improvement in at least one performance parameter by an order of magnitude
 - Develop path to a commercializable product
- Project currently in its third year
 - <http://psec.uchicago.edu/>

Large Area Picosecond Photodetector Collaboration

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 - 3 US states
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 - Photo
 - Univer
- Premise:
 - Apply nanotechnology methods to photo
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Goal: develop a family of large-area robust photo-detectors with *good position and timing resolution* that can be tailored for a wide variety of applications where large-area *economical* photon detection is needed.

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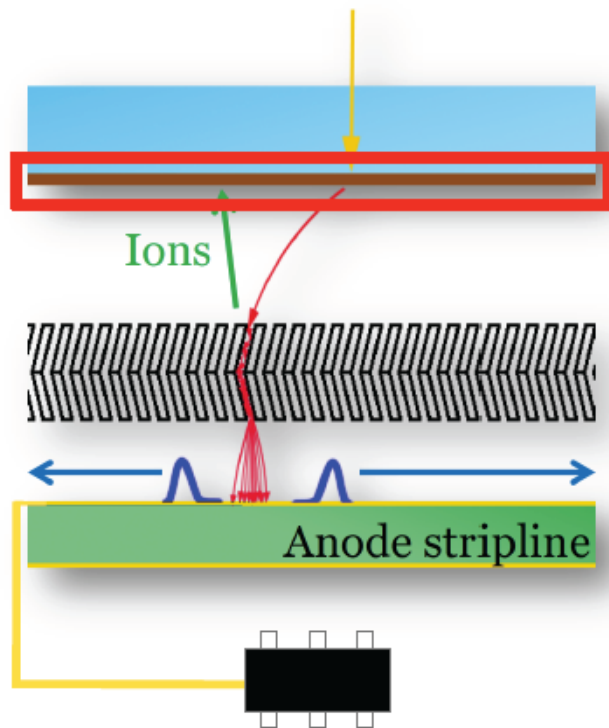
Synkera Technologies Inc., Longmont, CO

David Forbush, Tianchi Zhao

Department of Physics, University of Washington, Seattle, WA

LAPPD Deconstructed

8" Square Tile



1. Photo-Cathode (PC)

- Conversion of photons to electrons
- Engineer III-V materials to develop robust high QE photo-cathodes

2. Micro-Channel Plates

- Amplification of signal: two plates with tiny pores, held at high potential difference. Use Atomic Layer Deposition for emissive material on inert substrates to create avalanche

3. Electronics

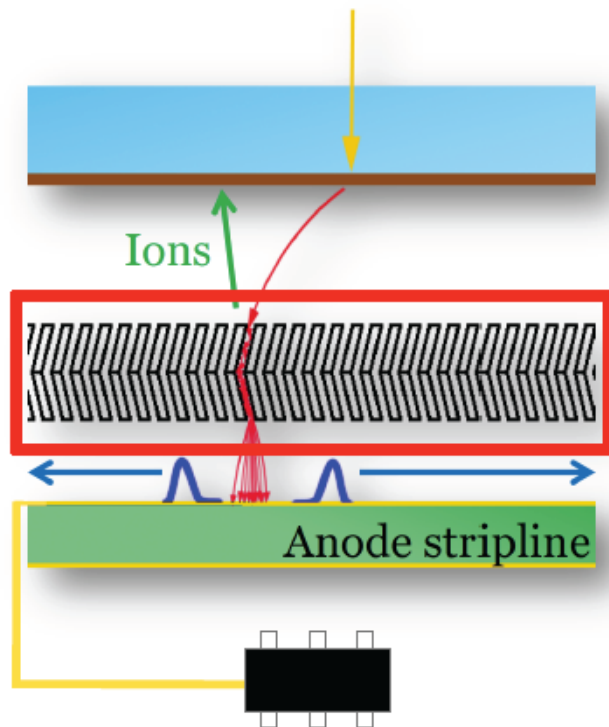
- Transmission line readout: 50 Ω scalable strip line, silk-screen printed on glass ground plane
- Readout at both ends with fast custom CMOS SCA chip with 10GHz waveform digitization

4. Hermetic Packaging

- Maintain vacuum and provide support. No internal connections; no penetrations

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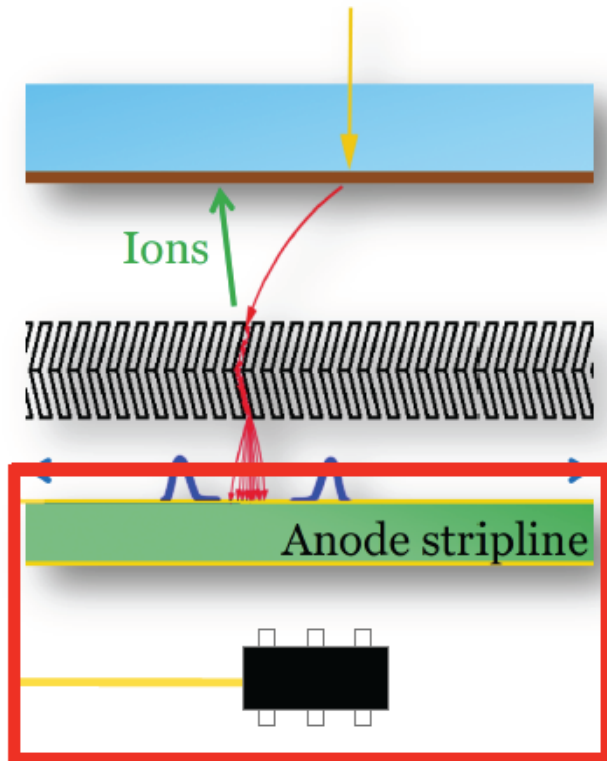
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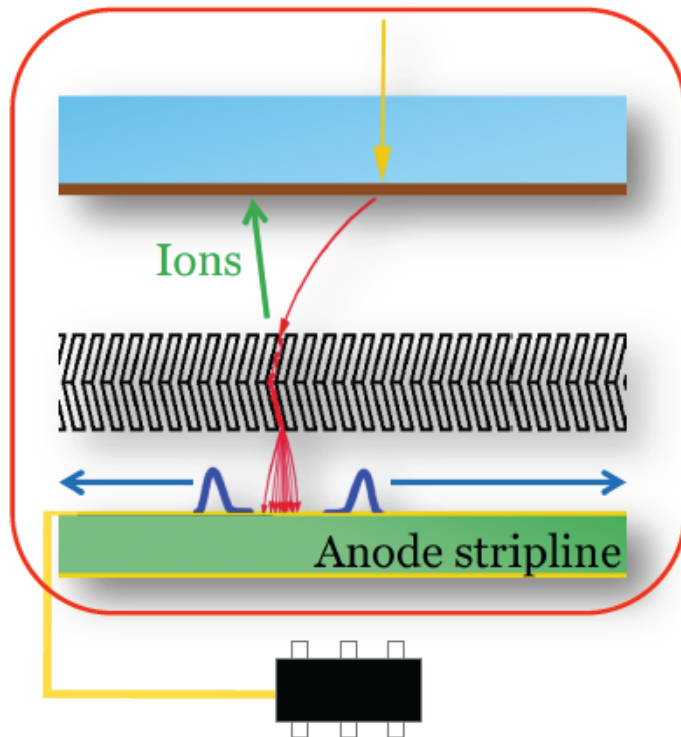
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The Previous Three Years

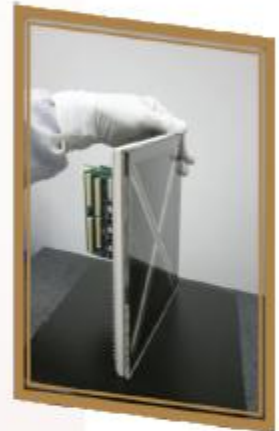
LAPPD program was a new instrumentation initiative, not an ongoing program; no pre-existing group, started with transient seed funding



R&D 100 Award

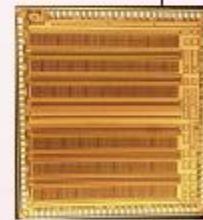


SBIR/STTR (\$3M)



Met all sub-component milestones for constructing full device

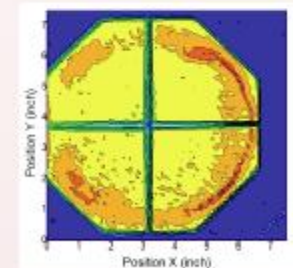
ALD Technology Licensed



PSEC4, fastest sampling chip, 17 GHz



MCP Technology select



7" Photocathode



t=0

t=1yr

t=2yr

t=3yr

time



Argonne 8" PhotoCathode Progress Summary

- Large area (7"X7") flat photocathode with average QE (~16%) was produced,
- Highest QE value was 22% QE of the photocathode is directly related to base Sb layer thickness.
- The optimized Sb thickness for KCs-Sb photocathode is around 78% transmission (@400nm).
- In related studies we used the BNL Synchrotron light source experiment and successfully saw the K diffusion process and K_2CsSb crystalline growth with X ray reflection/diffraction.

Next Steps

- More Reflection data on Sb films to calibrate the transmission
- Optimize the cathode recipe for higher QE cathode based on parameter studies & X ray reflection/diffraction data.
- Input findings into LAPPD sealed tube fabrication program



UCB 8" PhotoCathode Progress Summary

8" PC/Seal Test Chamber

- $<10^{-9}$ Torr base vacuum, RGA operational, fully baked
- 5mm thick, 8.7" polished B33 windows, NiCr border with "X"
- Successfully hot/vacuum sealed window to tube indium well.
- Deposited Na_2KSb photocathodes on 8" windows

- *~25% QE with good uniformity ($\pm 15\%$) and stability (>5 Mo)*
- *Can repeat successful process in different vacuum tanks*
- *RGA/pressure/temp/response record for entire process*

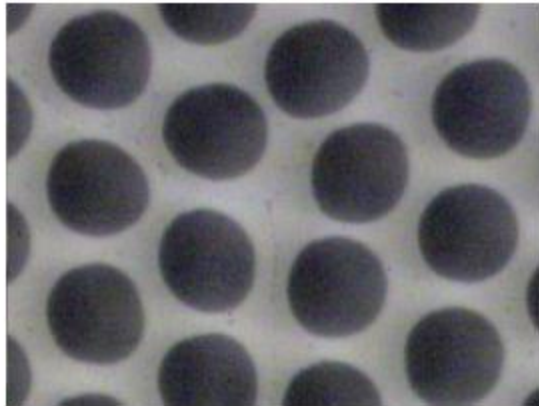
8" Sealed Tube Process Tank

- *$<10^{-9}$ Torr base vacuum, RGA operational, fully baked*
- *Deposited 1st cathode, optimization process underway*

Next Steps

- *Optimize cathode process in 8" Sealed Tube Tank*
- *Seal Na_2KSb photocathodes onto LAPPD devices*

MCP Development: Simplifying Construction



Conventional Pb-glass MCP

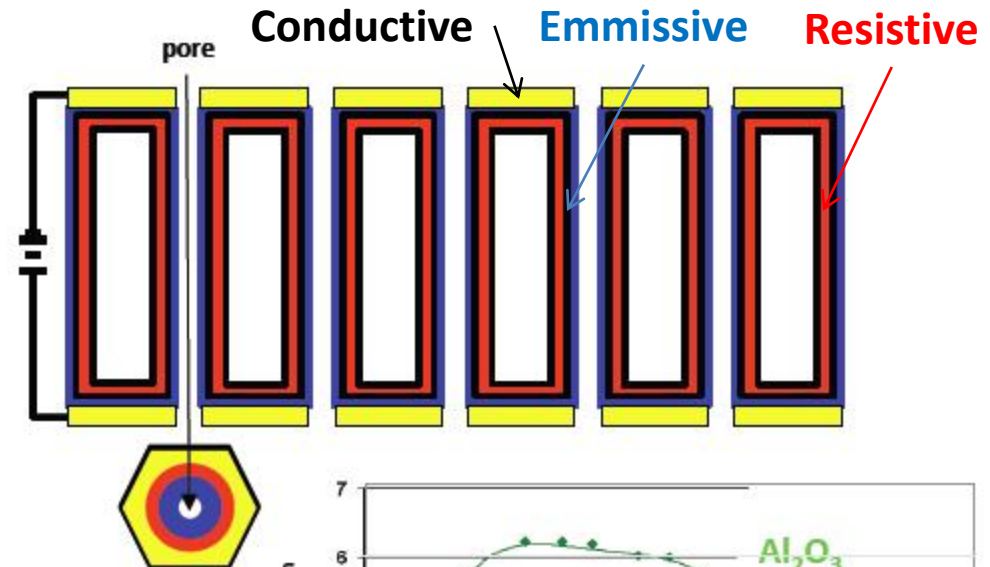


Incom Glass Substrate

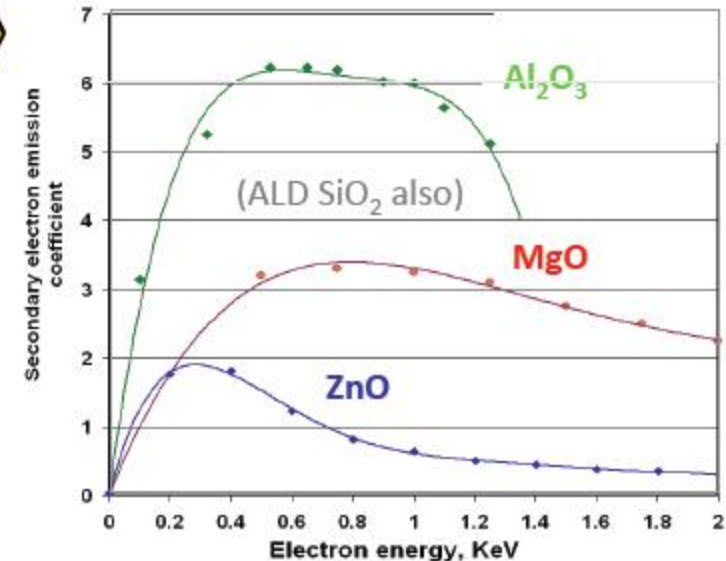
- Chemically produced and treated
- Pb-glass provides 3 functions:
 - Provides pores
 - Resistive layer supplies electric field in the pore
 - Pb-oxide layer provides secondary electron emission
- Separate the three functions:
 - Hard glass substrate provides pores
 - Separate Resistive and Emissive layer functions
 - Produce Tuned Resistive Layer (Atomic Layer Deposition, ALD) provides current for electric field
 - Specific Emitting layer provides secondary electron emission

MCP Fabrication with ALD

- Apply conductive coating for HV, using thermal evaporation or sputtering

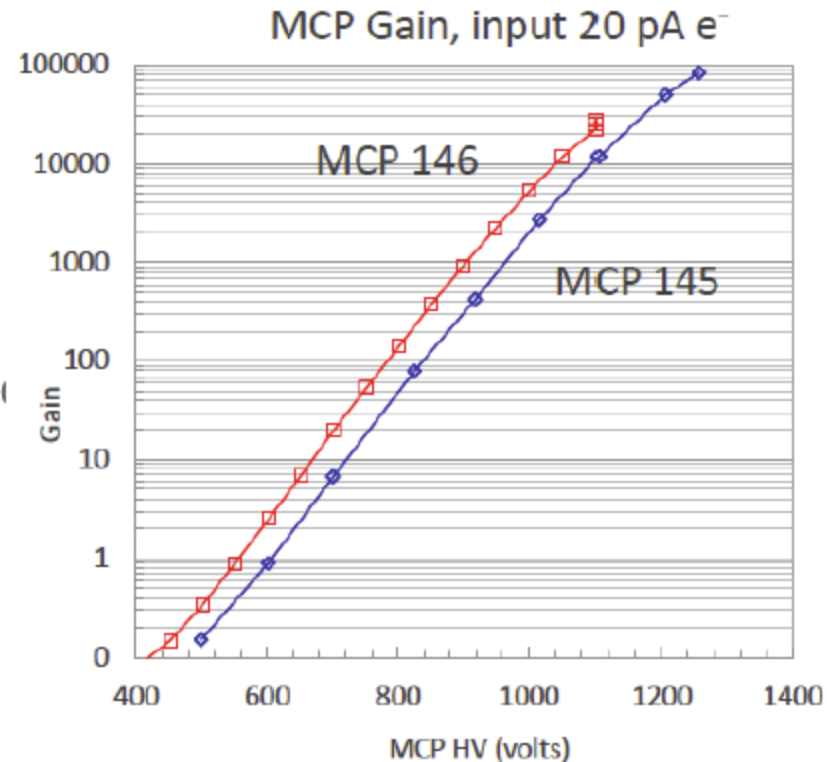


- First time applying new technology, a factor >5 improvement obtained in gain of ALD treated MCPs compared to commercial MCPs; area will be substantially increased



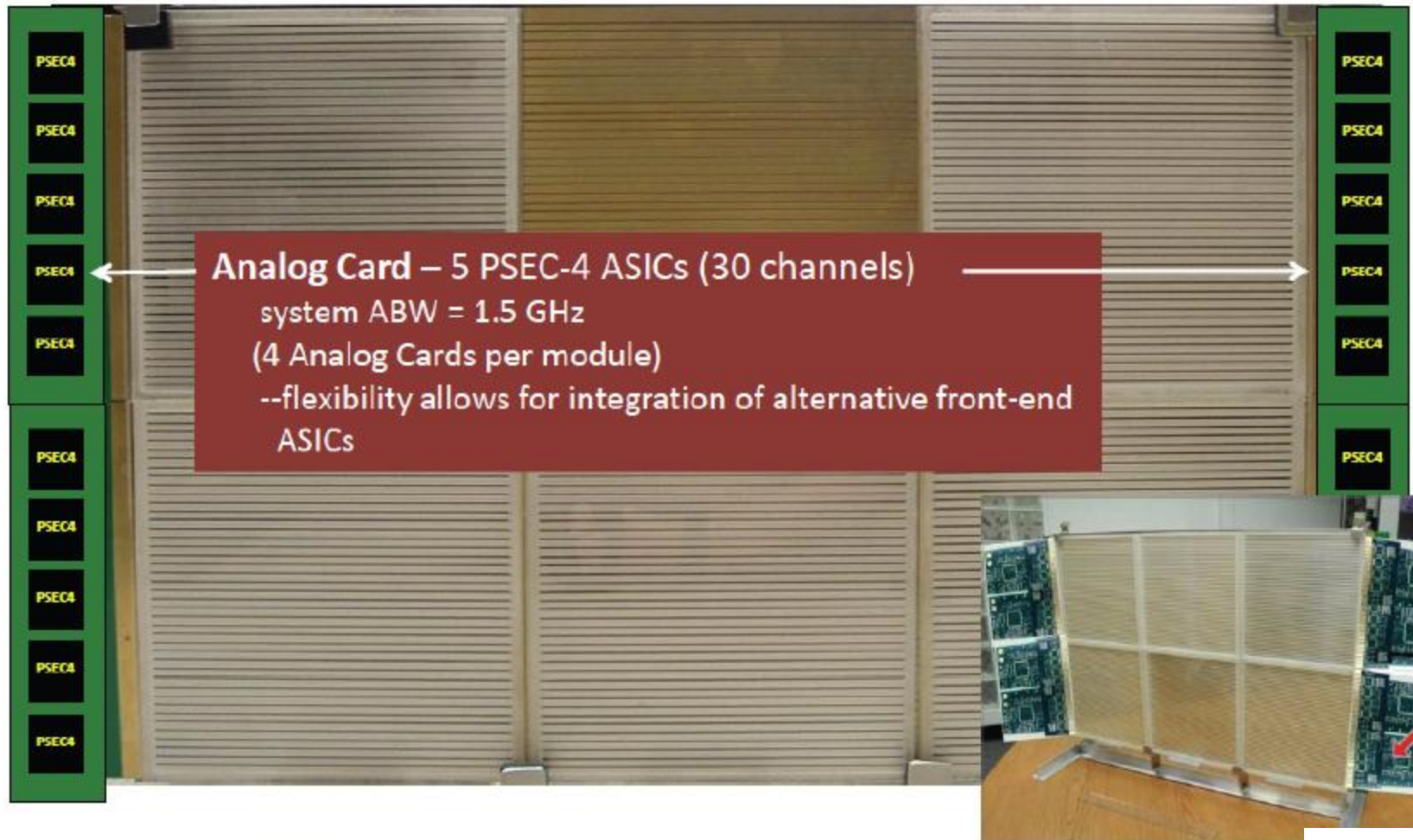
MCP Performance

- Single MCP, 33mm diameter, 20 μ m pore borosilicate MCP substrate, L:d = 60:1, 8 degree pore bias
- MCP disks functionalized with identical “Chemistry 2” resistive coating and Al₂O₃ SEE layer
- Single MCP tests in DC amplification mode for imaging and gain very similar to conventional MCPs.
- MCP pair gain of $> 10^7$ with $> 10^5$ in a single plate
 - Attractive for cost/simplicity



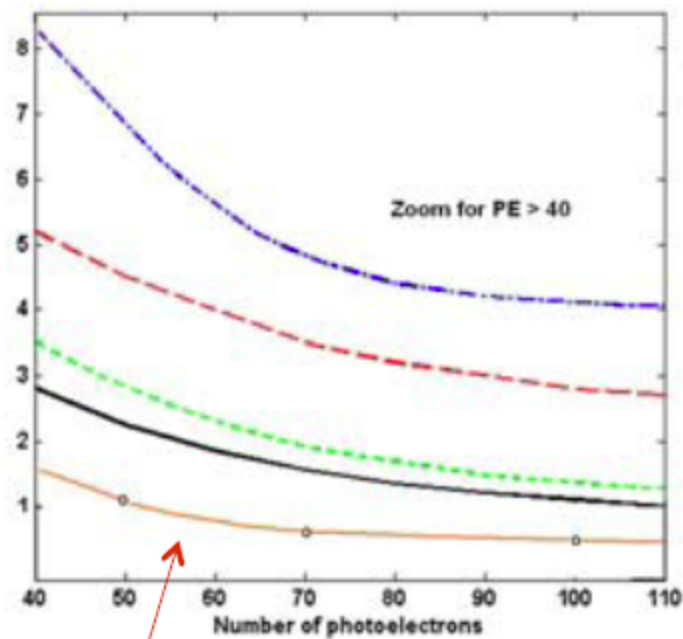
DAQ

- The DAQ system is targeted towards a module, which is six tiles (large area applications)

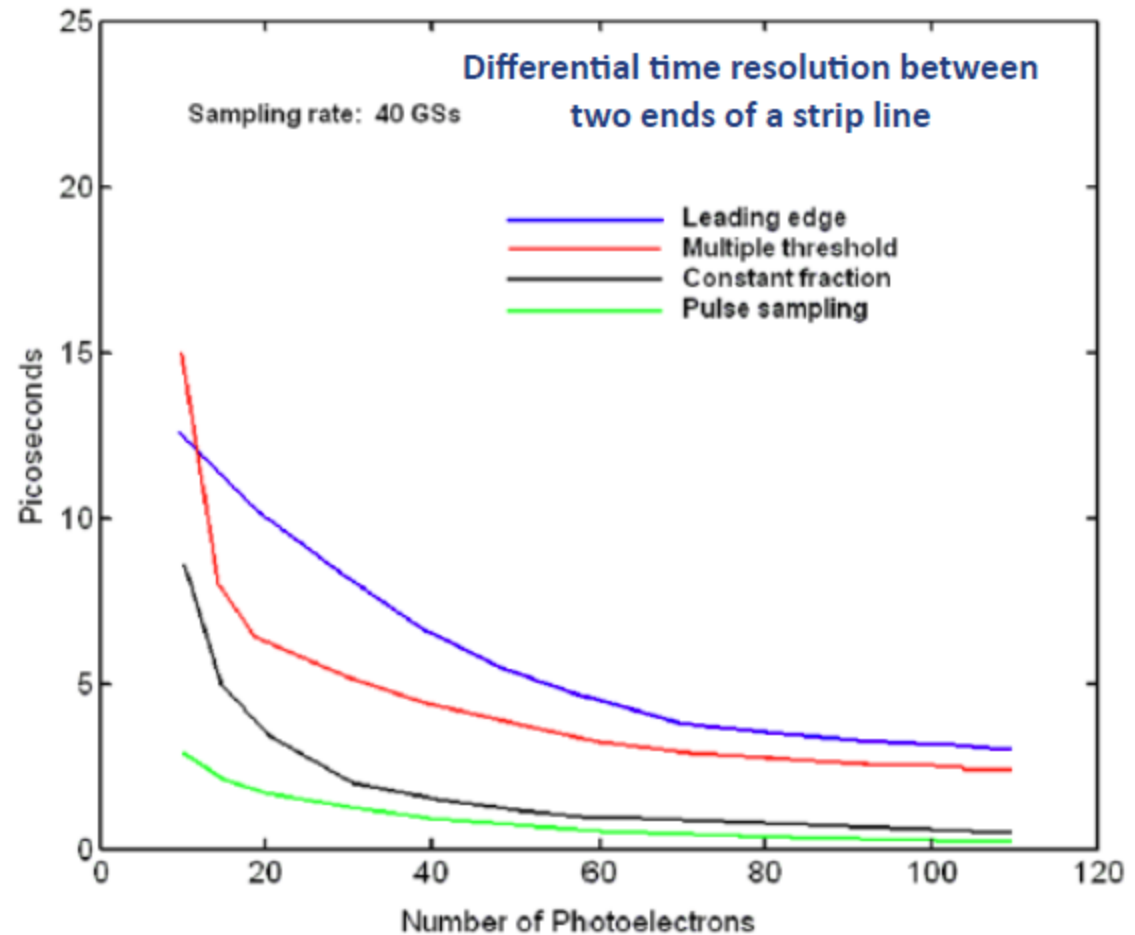


PSEC4 Waveform Sampling ASIC

- Resolution depends on # photoelectrons, analog bandwidth, and signal-to-noise.
- Simulations showed “pulse sampling” to give the best results



Measured!

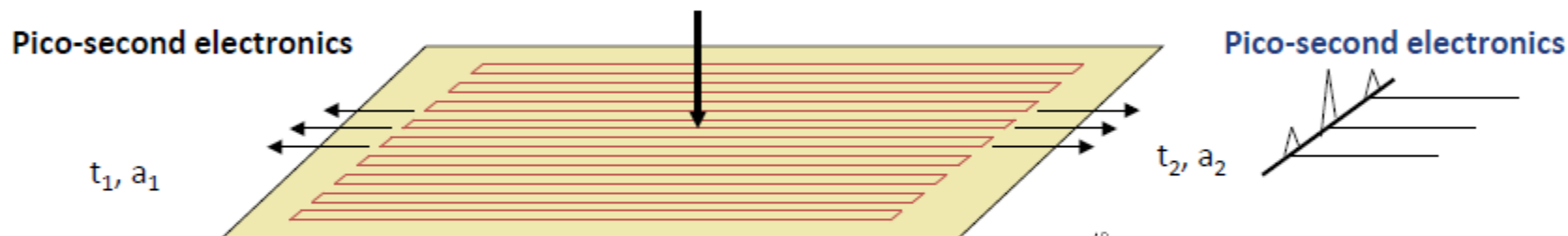


Picosecond timing and 2D position for large area detectors: delay lines and Waveform Sampling

Delay line readout and pulse sampling provide fast timing (2-10ps).

→ Delay lines should have a signal bandwidth matched to the detector

Fewer electronics channels for large area sensors



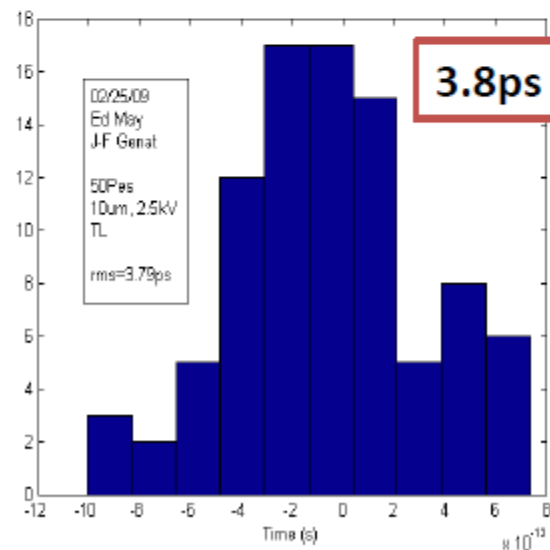
3.8 ps translates in 190 μm position resolution with 50 photo-electrons

$$\begin{aligned} \frac{1}{2} (t_1 + t_2) &= \text{time} \\ v(t_1 - t_2) &= \text{longitudinal position} \\ \frac{\sum \alpha_i a_i}{\sum \alpha_i} &= \text{transverse position} \end{aligned}$$

The electronics contribution to spread is small:

$$3.8\text{ps} / \sqrt{2} = 2.7\text{ps},$$

$$\text{For 50PEs, MCP is } 30\text{ps} / \sqrt{50} = 4.2\text{ps, equal at 100 PE}$$



Facilities for MCP-PMT Fabrication

- ▶ Space Sciences Laboratory/Berkeley
 - **Large Process Tank ready for first 8" tube fabrication**
 - Ceramic or Glass body
 - Ceramic body process fully specified with most steps qualified
 - Glass body process is beginning to be qualified
 - Na₂KSb photocathode with QE > 20%
- ▶ Argonne
 - Design work for 8" vacuum transfer system is ongoing with complete design anticipated for late spring 2013 and construction through mid-2014
 - Initially Glass body production of 8"×8" pinless 30-anode strip line design with indium seal
 - Thermopressure seal; parallel backup is hot pre-tinned indium seal
 - Adaptable for fabrication of alternative formats, photocathodes, ALD materials
 - K₂CsSb photocathode
 - Existing 4" vacuum transfer system in process of modification to proof process steps on smaller 2.5" format
 - Parts handling and processing generally directly scales to 8" format. Photocathode process will likely require formulation changes



Tube Production Plan for Next 3 Years

▶ Space Science Laboratory/Berkeley

- Year 1
 - First sealed ceramic tube. Process Development. Continue with 1–2 more ceramic tubes
 - First glass body tube.
- Year 2
 - Continued ceramic tube fabrication (2–3) & improvement/optimization
 - Continued glass body tube fabrication (1–2).
- Year 3
 - Ceramic tubes and/or systems customized for early adopter; 1 per 4 week cycle
 - Glass tubes by request

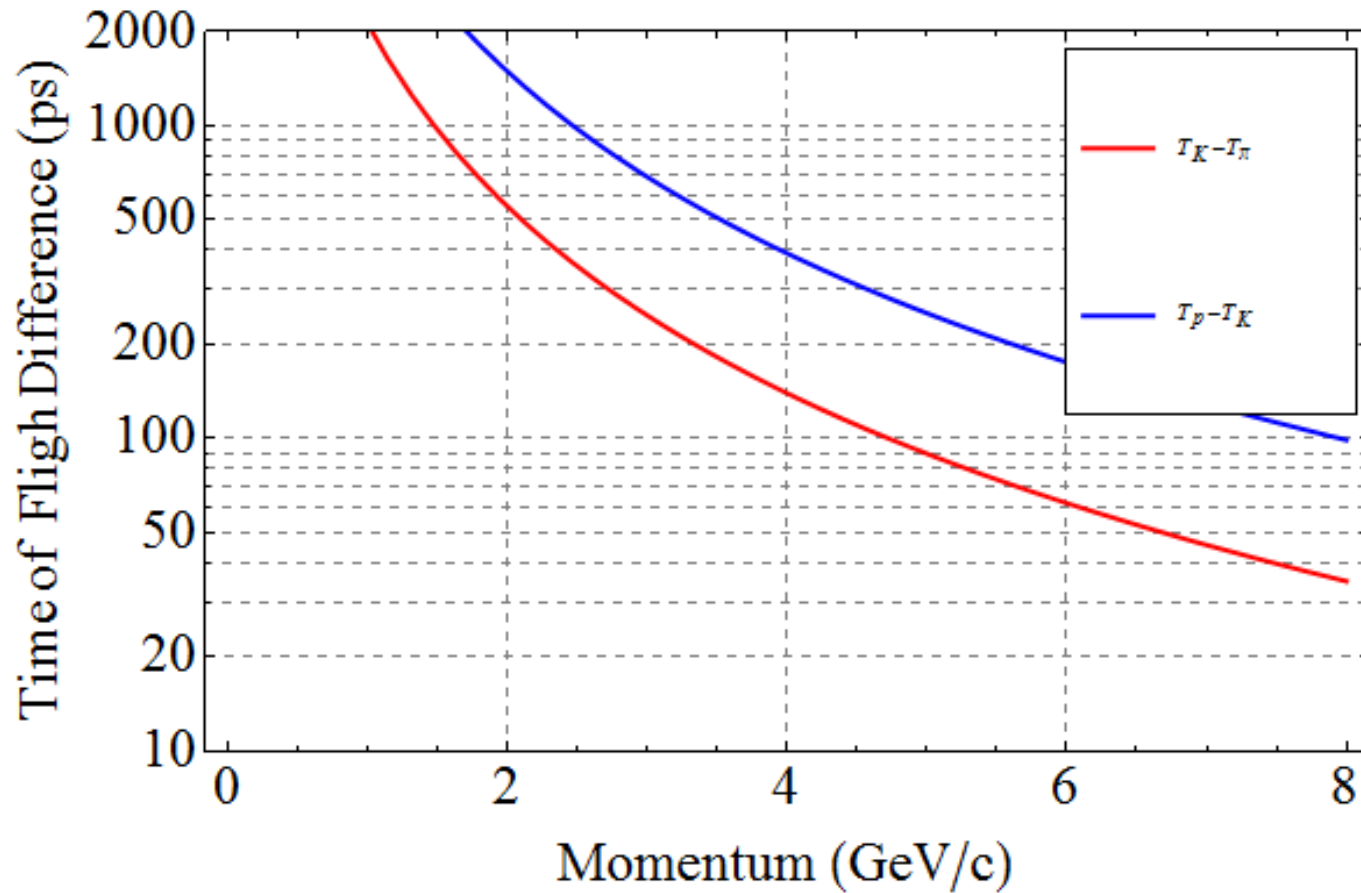
▶ Argonne National Laboratory†

- Year 1
 - Complete 8" Single Tile Processing System design, begin procurement and assembly
- Year 2
 - Complete assembly of 8" STPS, demonstrate individual processing steps (sample handling, photocathode shoot, baking & scrubbing, tube sealing)
 - Fabricate first 8" glass body tube
- Year 3
 - Establish routine production ramping up to 1 tube/2 week cycle

† need sealed-tube facility manager with phototube production experience



PID with TOF at 6 meters



Other Important Numbers

- MCP life time: $\gg 0.01 \text{ C/cm}^2$
 - 10^6 gain $\rightarrow 6 \times 10^{10} \text{ PE/cm}^2$ ($1 \text{ kHz/cm}^2 \rightarrow 700 \text{ days}$)
- Noise Level: $< 0.1/\text{cm}^2/\text{s}$
 - comparable to cosmic
- Saturation Current (from Hamamatsu): $> 0.5 \sim 5 \times 10^{-7} \text{ A/cm}^2$
 - 10^6 gain $\rightarrow 0.3 \sim 3 \times 10^6 \text{ PE/s/cm}^2$
- Radiation Hardness: Unknown

Resources

- DOE Review Dec 9, 2011
 - <https://twindico.hep.anl.gov/indico/conferenceDisplay.py?confId=740>
- DOE Review Dec 18, 2012
 - <https://twindico.hep.anl.gov/indico/conferenceDisplay.py?confId=1201>